IN THE CLAIMS:

Please cancel claims 3, 25, and 28 without prejudice or disclaimer of subject matter.

Please amend claims 5 and 26 as follows.

- 1 4. (Cancelled)
- 5. (Currently Amended) An image pickup device comprising:

a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit to read out the signal from said semiconductor area; and

a drive circuit coupled to said pixels and to output a <u>pulse wave form</u> signal for controlling said transfer switch so that a time during which said transfer switch changes from an ON state to an OFF state becomes longer than a time during which said transfer switch changes from the OFF state to the ON state.

- (Previously Presented) The device according to Claim 5, wherein said read unit
 includes an amplification transistor for amplifying and outputting the signal in said
 semiconductor area.
- (Previously Presented) The device according to Claim 5, wherein said photoelectric conversion unit includes an embedded photodiode.

 (Previously Presented) The device according to Claim 5, further comprising an analog/digital conversion circuit adapted to convert a signal from each of said plurality of pixels into a digital signal,

a signal processing circuit adapted to process the signal from said analog/digital conversion circuit, and

a recording circuit adapted to record the signal processed by said signal processing

9. (Withdrawn) An image pickup device comprising:

a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch adapted to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit adapted to read out the signal from said semiconductor area; and

a drive circuit adapted to control said transfer switch,

wherein a substantial driving force of said drive circuit for changing said transfer switch from an OFF state to an ON state is higher than a substantial driving force for changing said transfer switch from the ON state to the OFF state.

- (Withdrawn) A device according to Claim 9, wherein said read unit includes an amplification transistor for amplifying and outputting the signal in said semiconductor area.
- (Withdrawn) A device according to Claim 9, wherein said photoelectric conversion unit includes an embedded photodiode.

12. (Withdrawn) A device according to Claim 9, further comprising

an analog/digital conversion circuit adapted to convert a signal from each of said plurality of pixels into a digital signal,

a signal processing circuit adapted to process the signal from said analog/digital conversion circuit, and

a recording circuit adapted to record the signal processed by said signal processing

13. (Withdrawn) An image pickup device comprising:

a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch adapted to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit adapted to read out the signal from said semiconductor area; and

a drive circuit adapted to control said transfer switch,

wherein said transfer switch comprises a transistor of a first conductivity type, and said drive circuit includes at least a structure formed by connecting the transistors of the first conductivity type in series.

- 14. (Withdrawn) A device according to Claim 13, wherein said read unit includes an amplification transistor for amplifying and outputting the signal in said semiconductor area.
- (Withdrawn) A device according to Claim 13, wherein said photoelectric conversion unit includes an embedded photodiode.

16. (Withdrawn) A device according to Claim 13, further comprising an analog/digital conversion circuit adapted to convert a signal from each of said plurality of pixels into a digital signal,

a signal processing circuit adapted to process the signal from said analog/digital conversion circuit, and

a recording circuit adapted to record the signal processed by said signal processing

17. (Previously Presented): An image pickup device comprising:

a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit to read out the signal from said semiconductor area; and

a drive circuit coupled to said pixels to output a signal to control said transfer switch so that a fall speed Voff for changing said transfer switch from an ON state to an OFF state has a relation 10 V/µsec > Voff.

- 18. (Previously Presented): The device according to Claim 17, wherein said read unit includes an amplification transistor for amplifying and outputting the signal in said semiconductor area.
- (Previously Presented): The device according to Claim 17, wherein said photoelectric conversion unit includes an embedded photodiode.

20. (Previously Presented): The device according to Claim 17, further comprising an analog/digital conversion circuit adapted to convert a signal from each of said plurality of pixels into a digital signal,

a signal processing circuit adapted to process the signal from said analog/digital conversion circuit, and a recording circuit adapted to record the signal processed by said signal processing circuit.

21. (Withdrawn) An image pickup device comprising:

a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch adapted to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit adapted to read out the signal from said semiconductor area; and

a drive circuit adapted to control said transfer switch,

wherein said drive circuit includes a constant current circuit

- (Withdrawn) A device according to Claim 21, wherein said read unit includes an
 amplification transistor for amplifying and outputting the signal in said semiconductor area.
- (Withdrawn) A device according to Claim 21, wherein said photoelectric conversion unit includes an embedded photodiode.
 - 24. (Withdrawn) A device according to Claim 21, further comprising

an analog/digital conversion circuit adapted to convert a signal from each of said plurality of pixels into a digital signal.

a signal processing circuit adapted to process the signal from said analog/digital conversion circuit, and

a recording circuit adapted to record the signal processed by said signal processing circuit.

25. (Cancelled)

26. (Currently Amended) A drive method for an image pickup device including a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit to read out the signal from said semiconductor area, comprising:

an output step of outputting a <u>drive pulse wave form</u> signal to control said transfer switch so that a time during which said transfer switch changes from an ON state to an OFF state becomes longer than a time during which said transfer switch changes from the OFF state to the ON state.

27. (Previously Presented) A drive method for an image pickup device including a plurality of pixels each including a photoelectric conversion unit, a semiconductor area to which a signal from said photoelectric conversion unit is transferred, a transfer switch to transfer the signal from said photoelectric conversion unit to said semiconductor area, and a read unit to read out the signal from said semiconductor area, comprising:

an output step of outputting a drive signal to control said transfer switch so that a fall speed Voff for changing said transfer switch from an ON state to an OFF state has a relation 10 V/ μ sec > Voff.

28. (Cancelled)